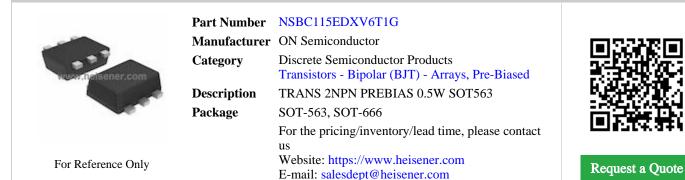


# NSBC115EDXV6T1G

### NSBC115EDXV6T1G Information



### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## NSBC115EDXV6T1G Specifications

Manufacturer Part Number	NSBC115EDXV6T1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Package	SOT-563, SOT-666
Series	-
Transistor Type	2 NPN - Pre-Biased (Dual)
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	100k
Resistor - Emitter Base (R2) (Ohms)	100k
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 5mA, 10V
Vce Saturation (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Current - Collector Cutoff (Max)	500nA
Frequency - Transition	_
Power - Max	500mW
Mounting Type	Surface Mount
Package / Case	SOT-563, SOT-666
Supplier Device Package	SOT-563
	Report errors?

### NSBC115EDXV6T1G Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### NSBC115EDXV6T1G Payment Methods



If you have any question about NSBC115EDXV6T1G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com